

## STPAC02F2

#### **IPAD™**

RF Detector for power amplifier control with internal temperature compensation

#### Main product characteristics

- 0.8 to 2.5 GHz frequency range
- Detection diode voltage drop compensation
- Temperature compensation
- Fast response time
- Low Power consumption
- Chip Scale device
- Low parasitic impedance
- Lead free package

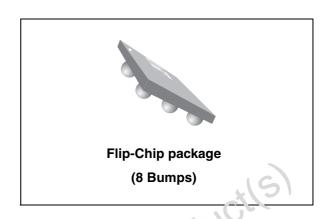
## **Description**

The STPAC02F2 is an integrated RF detector for power control chain. It has been developed to convert the RF signal coming from the external coupler into a DC signal usable by the mobile digital stage. It is based on the use of two similar diodes, one assuming the signal detection while the second one is used to compensate the ambient temperature effect. A biasing stage suppresses the detection diode drop voltage effect. The use of the IPAD technology allows the RF front-end designer to save PCB area and to drastically suppress the parasitic in ouctances of the package.

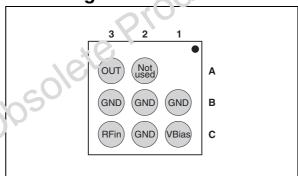
Target applications are callular phones and PDA using GSM, DCS PCS, AMPS, TDMA, CDMA and 800 MHz & 2000 MHz frequency ranges.

#### Benefits

► The use of IPAD technology allows the RF front-end designer to save PCB area and to drastically suppress the parasitic inductances.



### Pin configuration



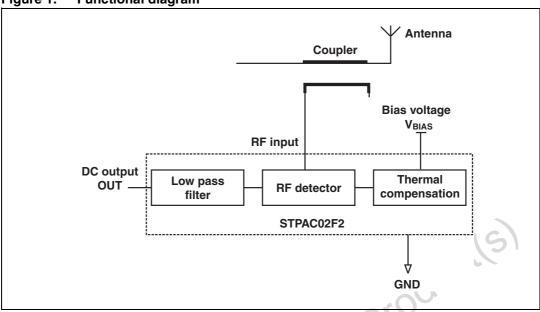
#### Order code

Part number	Marking		
STPAC02F2	RB		

Characteristics STPAC02F2

## 1 Characteristics

Figure 1. Functional diagram



**Table 1.** Absolute ratings  $(T_{amb} = 25^{\circ} C)$ 

Symbol	Parameter and test conditions	Value	Unit
V <sub>BIAS</sub>	Bias voltage	5	V
P <sub>RF</sub>	RF power at the RF input	20	dbm
F <sub>OP</sub>	Operating frequency range	0.8 to 2.5	GHz
V <sub>PP</sub>	ESD level as per MIL-STD 883E method 3015.7 notice 8 (HBM)	250	V
T <sub>OP</sub>	Operating temperature range	- 30 to + 85	°C
T <sub>STG</sub>	Storage temperature range	- 55 to 150	°C

# 1.1 Electrical characteristics $(T_{amb} = 25^{\circ} C)$

Table 2. Parameters related to bias voltage

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>BIAS</sub>	Operating bias voltage		2.3	2.8	3.3	V
I <sub>BIAS</sub>	Bias current	V <sub>BIAS</sub> = 3.3 V		1.1	1.6	mA

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STPAC02F2 Characteristics

Table 3. Parameters related to detection function (V<sub>BIAS</sub> = 2.8 V, DC output load = 200 k $\Omega$ )

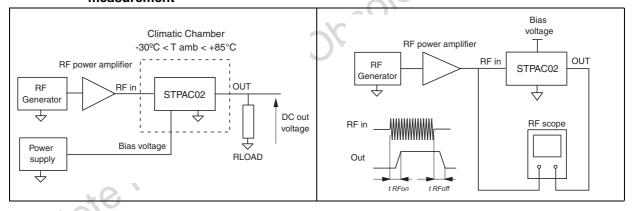
Symbol	Parameter	Test conditions	Min	Тур	Max	Unit	
	F = 1.75 GHz, P <sub>RF</sub> = 10 dbm		0.63	0.69	0.75		
l v	V <sub>DCout</sub> DC output voltage (see <i>Figure 2.</i> )	DC output voltage F = 1.75 GHz, P <sub>RF</sub> = - 20 dbm		0.20	0.22	0.24	V
V DCout		F = 0.9 GHz, P <sub>RF</sub> = 10 dbm	0.69	0.75	0.83	V	
	F = 0.9 GHz, P <sub>RF</sub> = - 20 dbm	0.20	0.22	0.24			
$\Delta V_{DCout}$	DC output voltage variation (see <i>Figure 2</i> .)	2.3 V < V <sub>BIAS</sub> < 3.3 V, F = 1.85 GHz, P <sub>RF</sub> =10 dbm		100		mV	

Table 4. Parameters related to response time ( $V_{BIAS} = 2.8 \text{ V}$ , DC output load = 200 k $\Omega$ )

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>VBIAS</sub>	Delay at V <sub>BIAS</sub> ON (see <i>Figure 4</i> .)	V <sub>BIAS</sub> from 0 to 3 V		1	1.0	
t <sub>RFon</sub>	Delay at RF ON (see <i>Figure 3</i> .)	P <sub>RF</sub> from 0 to 20 dbm		0.2	Cil	V
t <sub>RFoff</sub>	Delay at RF OFF (see <i>Figure 3.</i> )	P <sub>RF</sub> from 20 to 0 dbm		0.2	5	

Figure 2. V<sub>DC</sub> output measurement circuit and temperature compensation measurement

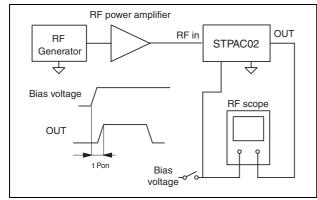
Figure 3. RF Power ON/OFF response time set-up



Characteristics STPAC02F2

Figure 4. Power supply turn ON response time

Figure 5. Temperature sensitivity versus RF Power in (V<sub>BIAS</sub> = 2.8 V, Freq. = 900 MHz)



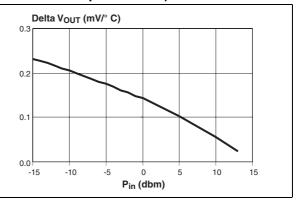
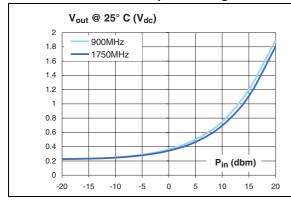


Figure 6. STPAC02 Output voltage at wide RF power range

Figure 7. Power detector sensitivity at wide RF power range



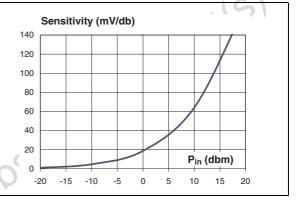
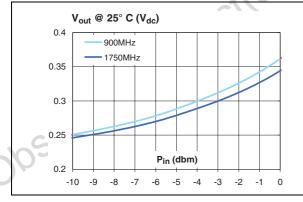
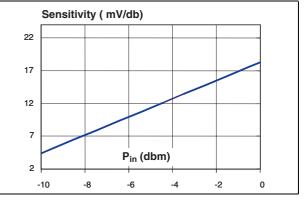


Figure 8. STPAC02 Output voltage at low RF power

Figure 9. Power detector sensitivity at low RF power





## 2 Packaging information

Figure 10. Flip-Chip dimensions

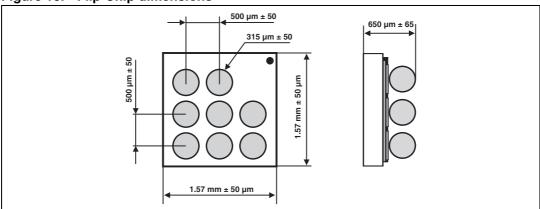


Figure 11. Foot print recommendations Figure 12. Marking

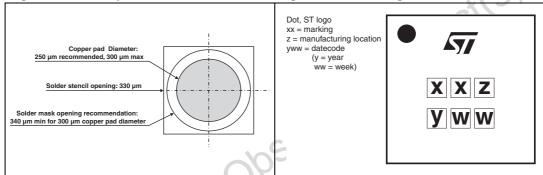
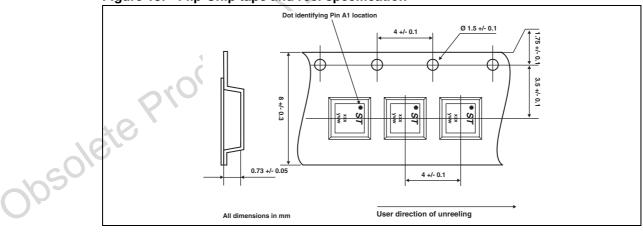


Figure 13. Flip-Chip tape and reel specification



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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Ordering information STPAC02F2

## 3 Ordering information

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STPAC02F1	RB	Flip-Chip	3.3 mg	5000	Tape and reel

Note: More packing informations are available in the application notes:

AN1235: "Flip-Chip: Package description and recommendations for use"

AN1751: "EMI Filters: Recommendations and measurements"

## 4 Revision history

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	Date	Revision	Changes
	16-May-2006	1	Initial release.
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Obsole	ite Pro	ducil	5) - 0105010

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